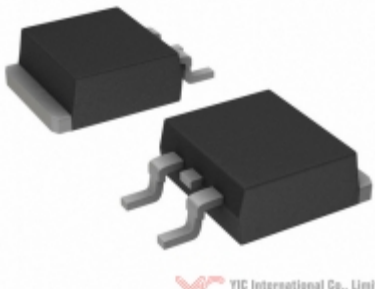
	<h2 style="color: #E67E22;">FQB7N60TM</h2>
 <p>Image may be representation. See specs for product details.</p>	<b>Hersteller-Teilenummer:</b> <a href="#">FQB7N60TM</a>
	<b>Hersteller / Marke:</b> <a href="#">Fairchild/ON Semiconductor</a>
	<b>Teil der Beschreibung:</b> MOSFET N-CH 600V 7.4A D2PAK
	<b>Datenblätter:</b>  <a href="#">FQB7N60TM.pdf</a>
	<b>RoHs Status:</b> Bleifrei / RoHS-konform
	<b>Lagerzustand:</b> New original, 15847 pcs Stock Available.
<b>Liefern von:</b> Hong Kong	
<b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS	

### Spezifikationen

Teilenummer	<a href="#">FQB7N60TM</a>
Hersteller	<a href="#">Fairchild/ON Semiconductor</a>
Beschreibung	MOSFET N-CH 600V 7.4A D2PAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	15847 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D <sup>2</sup> PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 142W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	7.4A (Tc)
Rds On (Max) @ Id, Vgs	1 Ohm @ 3.7A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	38nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1430pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Original-Reel®















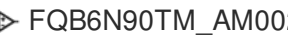



































FQB7N60TM ist neu im Original, Suche FQB7N60TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB7N60TM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB7N60TM: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FQB7N65C</b> FAIRCHILD FQB7N65C FAIRCHILD</p>	 <p><b>FQB7N60TM_WS</b> Fairchild/ON Semiconductor MOSFET N-CH 600V 7.4A D2PAK</p>	 <p><b>FQB7N60</b> FSC FQB7N60 FSC</p>	 <p><b>FQB7N40</b> IR FQB7N40 IR</p>
 <p><b>FQB7N60TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 7.4A D2PAK</p>	 <p><b>FQB7N30TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 300V 7A D2PAK</p>	 <p><b>FQB7N65</b> FSC FSC TO-263</p>	 <p><b>FQB7N60TM-WS</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 7.4A D2PAK</p>

### heiße Teile

Mehr

 FQB6N40C	 FQB6N40CF	 FQB6N40CTM	 FQB6N40CTM	 FQB6N50TM
 FQB6N50TM	 FQB6N60C	 FQB6N60CTM	 FQB6N60CTM	 FQB6N60TM
 FQB6N60TM	 FQB6N70TM	 FQB6N70TM	 FQB6N90TM	 FQB6N90TM_AM002
 FQB6N90TM_AM002	 FQB7042FB	 FQB7045FB	 FQB70N03	 FQB70N06
 FQB70N08	 FQB70N10TM	 FQB7N10L	 FQB7N20L	 FQB7N60TM
 FQB7N65C	 FQB7N65CTM	 FQB7N65CTM	 FQB7P20TM	 FQB7P20TM
 FQB85N06	 FQB85N06TM	 FQB8N25TM	 FQB8N25TM	 FQB8N60C
 FQB8N60CFTM	 FQB8N60CFTM	 FQB8N60CTM	 FQB8N60CTM	 FQB8N60TM
 FQB8N90CTM	 FQB8N90CTM	 FQB8P10TM	 FQB8P10TM	 FQB8P10TM-NL
 FQB9N08L	 FQB9N08LTM	 FQB9N08LTM	 FQB9N25C	 FQB9N25CTM

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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